HALOGEN

**FREE** 



## Vishay General Semiconductor

# Trench MOS Barrier Schottky Rectifier for PV Solar Cell Bypass Protection

Ultra Low  $V_F = 0.34 \text{ V}$  at  $I_F = 2.5 \text{ A}$ 

TMBS® TO-263AB



PRIMARY CHARACTERISTICS				
Package	TO-263AB			
I <sub>F(AV)</sub> 2 x 5.0 A				
V <sub>RRM</sub>	45 V			
I <sub>FSM</sub>	100 A			
V <sub>F</sub> at I <sub>F</sub> = 5.0 A	0.41 V			
T <sub>OP</sub> max. (AC mode)	150 °C			
T <sub>J</sub> max. (DC forward current)	200 °C			
Diode variation	Common cathode			

#### **FEATURES**

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- · High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- T<sub>J</sub> 200 °C max. in solar bypass mode application
- Material categorization: For definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **TYPICAL APPLICATIONS**

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

#### **MECHANICAL DATA**

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VBT1045CBP	UNIT	
Maximum repetitive peak reverse voltage		$V_{RRM}$	45	V	
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub> <sup>(1)</sup>	10	А	
	per diode		5		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	100	А	
Operating junction and storage temperature range (AC mode)		T <sub>OP</sub> , T <sub>STG</sub>	- 40 to + 150	°C	
Junction temperature in DC forward current without reverse bias, $t \le 1 \text{ h}$		T <sub>J</sub> <sup>(2)</sup>	≤ 200	°C	

#### **Notes**

<sup>(1)</sup> With heatsink

<sup>(2)</sup> Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 2.5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.44	-	V
	$I_F = 5.0 \text{ A}$			0.49	0.58	
	I <sub>F</sub> = 2.5 A	T <sub>A</sub> = 125 °C		0.34	-	
	$I_F = 5.0 \text{ A}$			0.41	0.50	
Reverse current per diode	V <sub>R</sub> = 45 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	-	500	μΑ
	$V_R = 45 \text{ V}$ $T_A = 125 ^{\circ}$	T <sub>A</sub> = 125 °C		5	15	mA

#### **Notes**

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	VBT1045CBP	UNIT		
Typical thermal resistance	per diode	$R_{ heta JC}$	3.5	- °C/W	
	per device		2.5		

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VBT1045CBP-M3/4W	1.38	4W	50/tube	Tube	
TO-263AB	VBT1045CBP-M3/8W	1.38	8W	800/reel	Tape and reel	

#### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

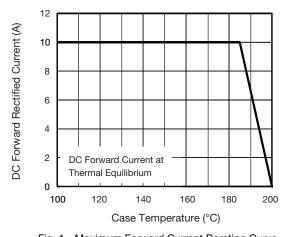


Fig. 1 - Maximum Forward Current Derating Curve

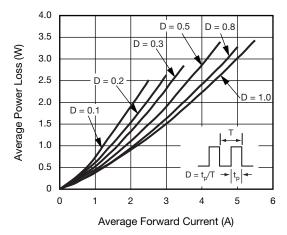


Fig. 2 - Forward Power Loss Characteristics Per Diode



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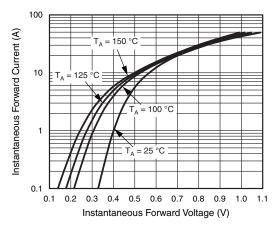


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

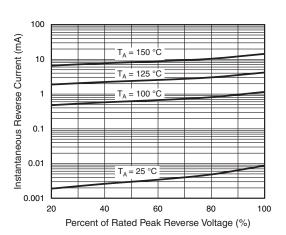


Fig. 4 - Typical Reverse Characteristics Per Diode

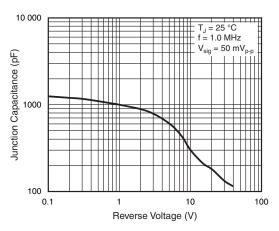


Fig. 5 - Typical Junction Capacitance Per Diode

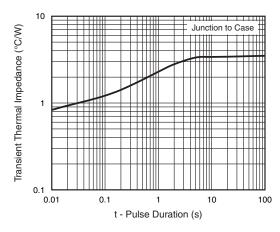
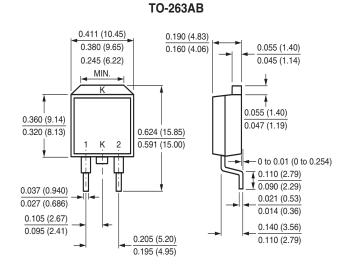
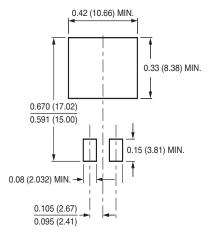


Fig. 6 - Typical Transient Thermal Impedance Per Diode

#### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



#### **Mounting Pad Layout**





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VBT1045CBP-E3/4W